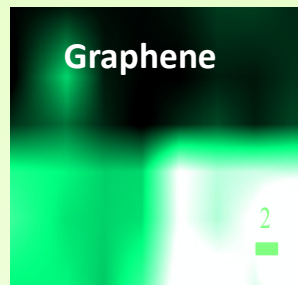
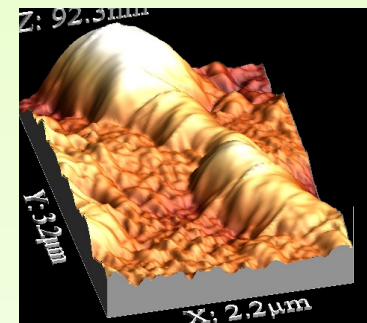


Efficient Combination of Interference and Plasmon Resonance Raman Amplifications by Optimized Heterostructures for Optical microscopy and Molecule Detection

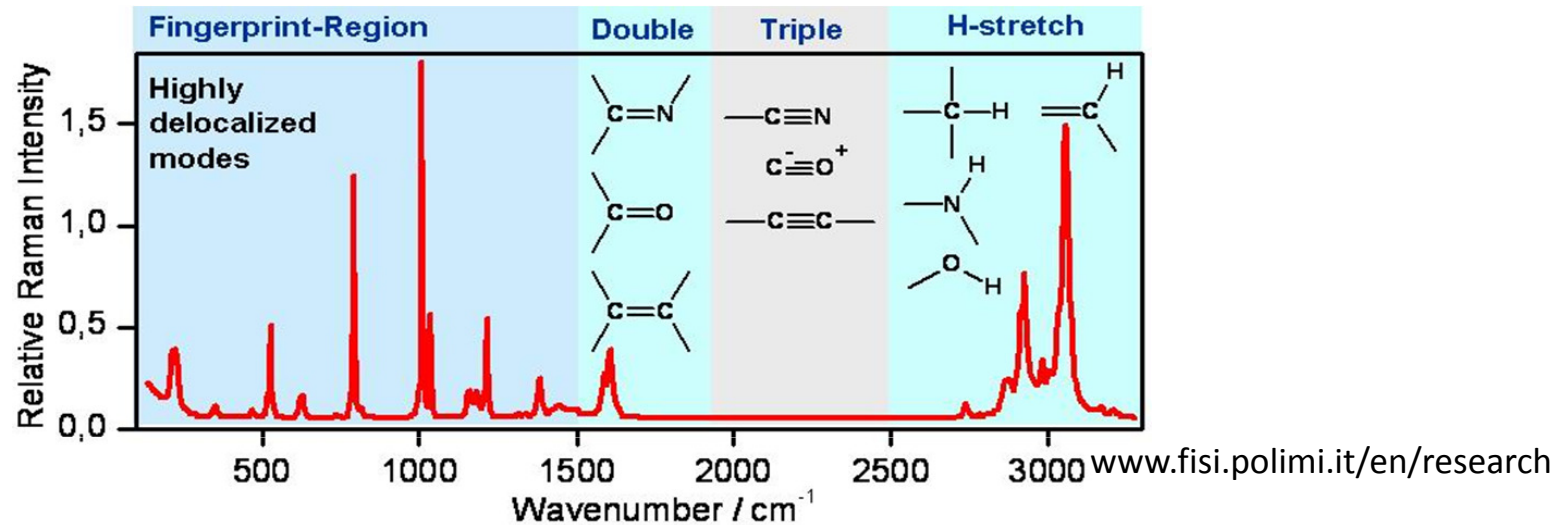


Montse Aguilar-Pujol
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Why Raman spectroscopy?

- * It is specific – the vibration spectrum is a finger print of each molecule



- * Non destructive
- * Sub-micron resolution, down to 10 nm for special configuration (TERS)
- * Quite high penetration depth
- * Label-free imaging method

BUT Very low cross section. About 10^{10} to 10^{12}
lower than IR absorption cross section

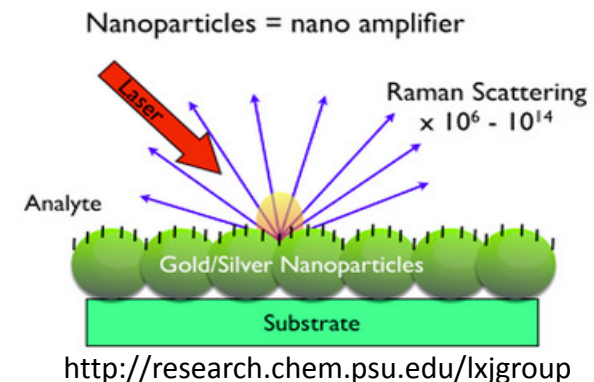
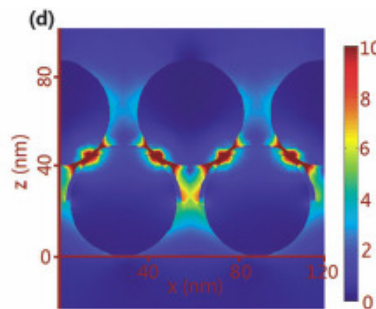
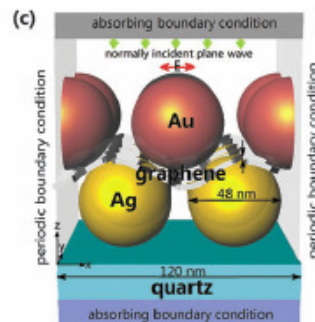
How can Raman signal be increased ?

Resonant Raman scattering

Choose the adequate excitation wavelength (at absorption wavelengths of the analyte). When the energy of the incident laser light coincides with an electronic transition the Raman intensity increases orders of magnitude.

Surface Enhanced Raman Spectroscopy - SERS

Enhancement related to localized **surface plasmon resonance** from metal NPs and to “**hot spots**”

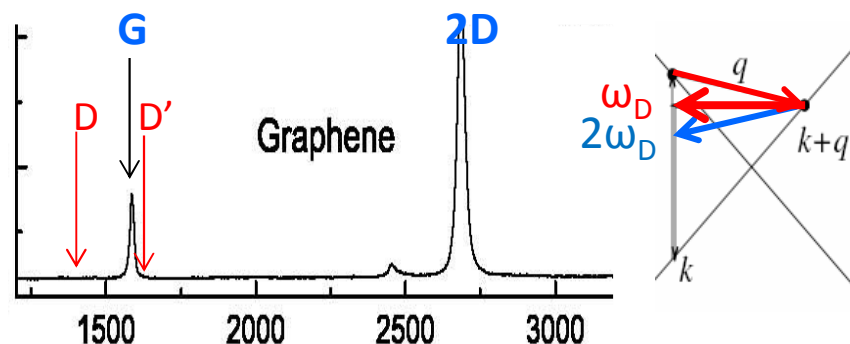


Interference Enhanced Raman Spectroscopy - IERS

See later....

The role of Graphene in SERS

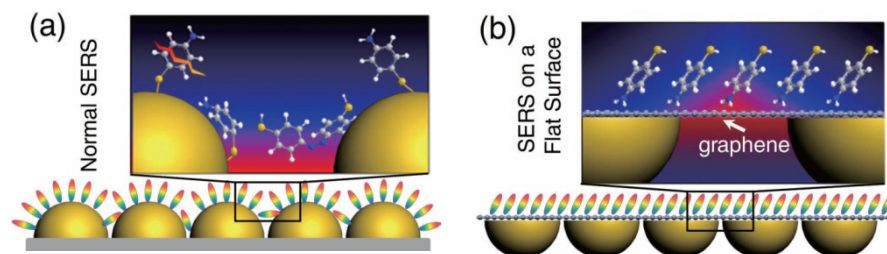
Raman of graphene is **resonant** and very sensitive to changes in electronic structure, presence of defects, strain,...**useful to probe its environment**



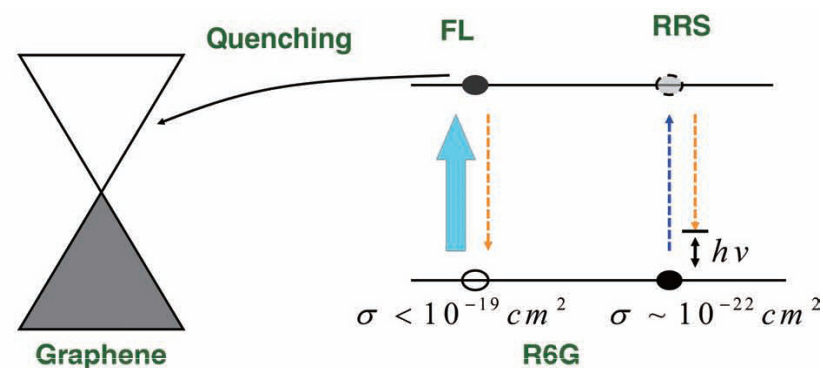
GERS: Chemical enhancement related to **graphene**.

Good **compatibility** of graphene with biological material.
Graphene creates uniform electrical field distribution

Provides a flat bio-compatible surface

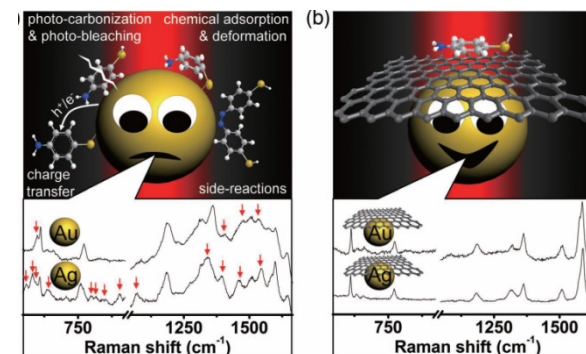


Graphene as a substrate: **fluorescence quenching** for molecules, especially limiting in resonant conditions



Xie et al. *J. Am. Chem. Soc.* 2009 , 131

Protects and stabilizes the NPs



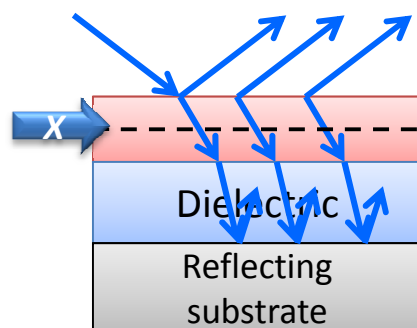
Xu J. Kong , et al . *PNAS* **2012**

Interference Enhanced Raman Spectroscopy - IERS

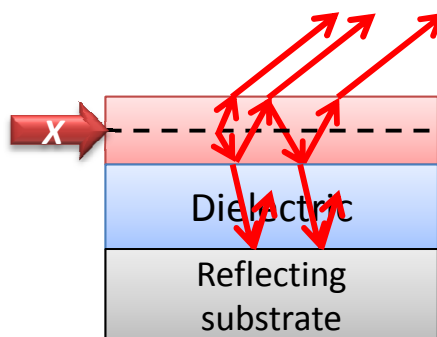
Multiple reflections at the interfaces induce interference effect for:

Multiple layers: Transfer matrix method

Absorbed incident light



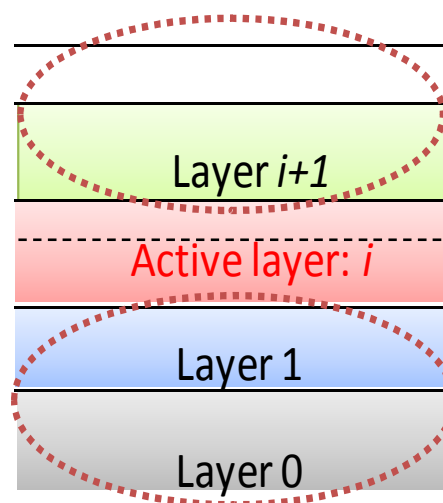
Raman scattered light



U_1 : Amplitud of Upwards travelling wave

D_1 : Amplitud of Downwards travelling wave

M_i : transforms amplitudes $i+1 \rightarrow i$



$U_i \uparrow \quad D_i \downarrow$

$\uparrow \quad \downarrow$

$U_1 \uparrow \quad D_1 \downarrow$

$1 \uparrow \quad r \downarrow$

$$\begin{pmatrix} U_i \\ D_i \end{pmatrix} = M_i \begin{pmatrix} U_{i+1} \\ D_{i+1} \end{pmatrix}$$

$$M^U = M_i M_{i+1} \dots M_{n-1}$$

$$M^L = M_0 M_1 \dots M_{i-1}$$

$$M = \begin{pmatrix} M_{00} & M_{01} \\ M_{10} & M_{11} \end{pmatrix}$$

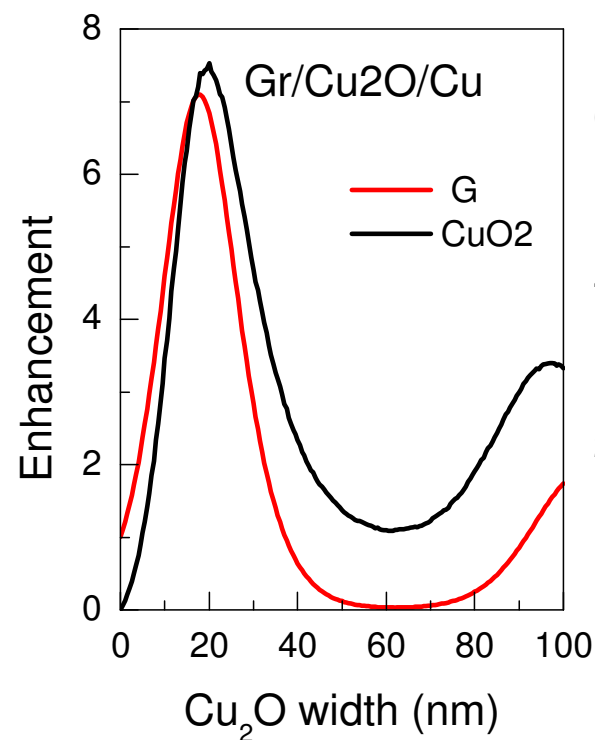
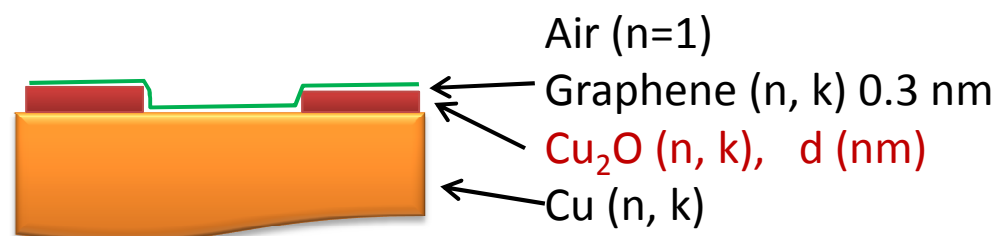
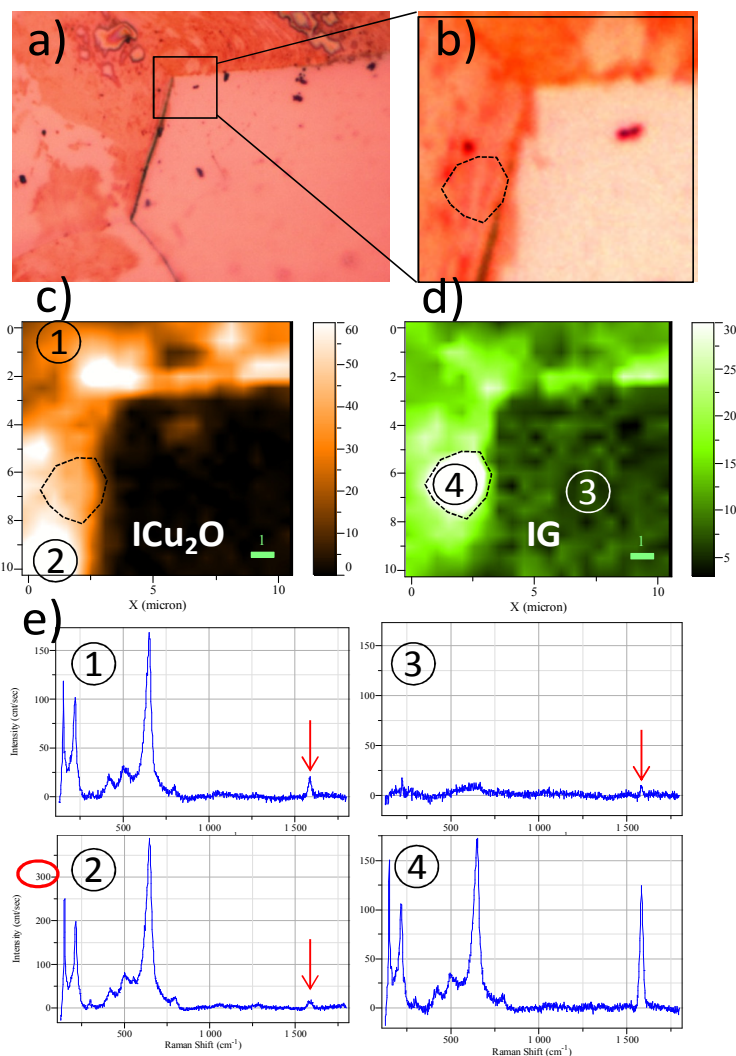
$$F_{sc} = F_{ab} (M_{00}^L M_{11}^L - M_{10}^L M_{01}^L)$$

$$F_{ab} = \frac{e^{-i\delta x} M_{00}^U + e^{i\delta x} M_{10}^U}{e^{-i\delta} M_{00}^U M_{00}^L + e^{i\delta} M_{10}^U M_{01}^L}$$

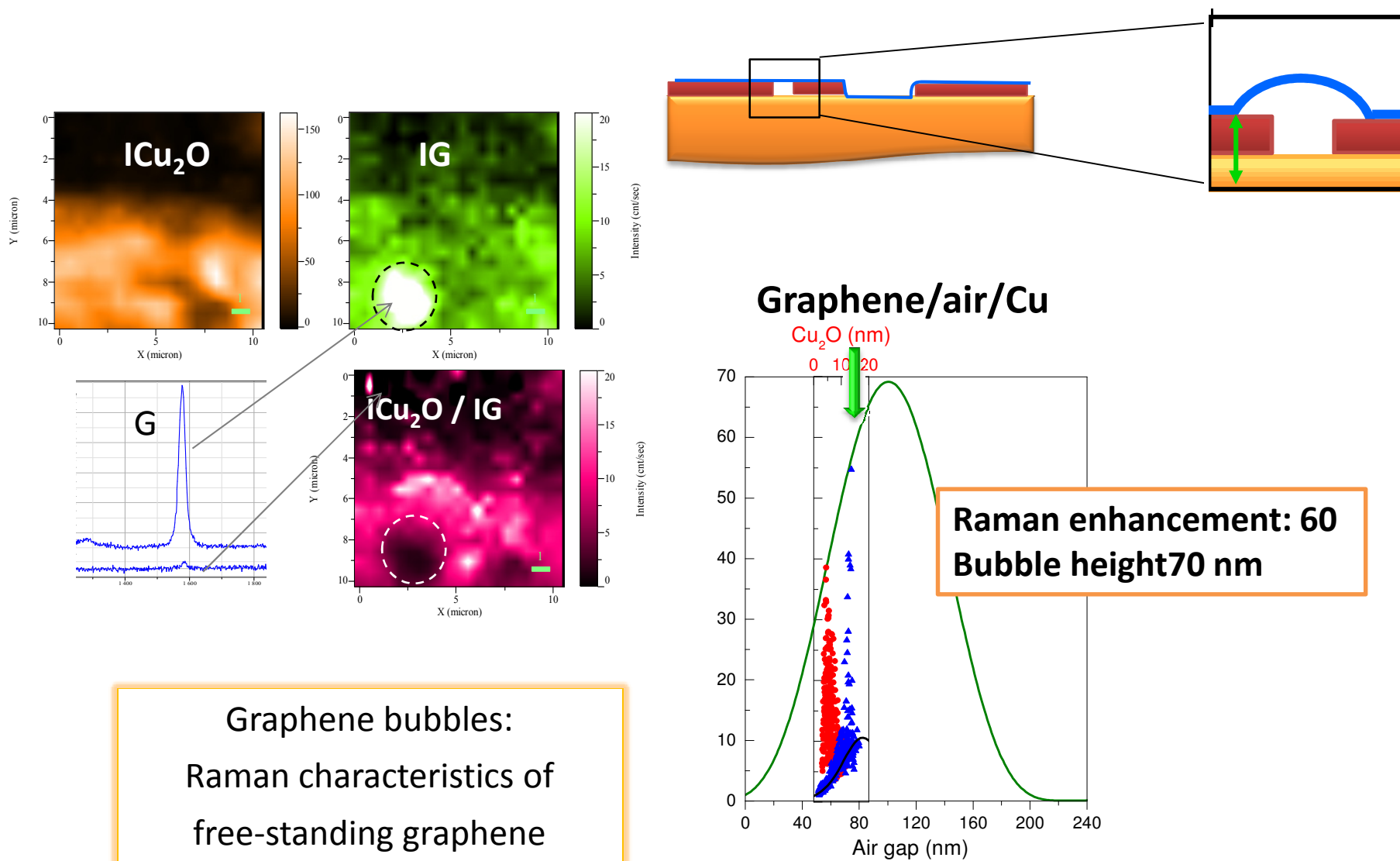
R. Ramírez-Jiménez et al. **Carbon** 105, 556 (2016)

1- Raman Enhancement by Interference in graphene

Graphene on Cu foil after several months



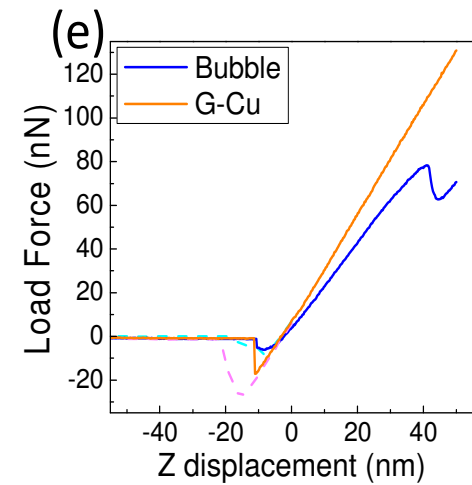
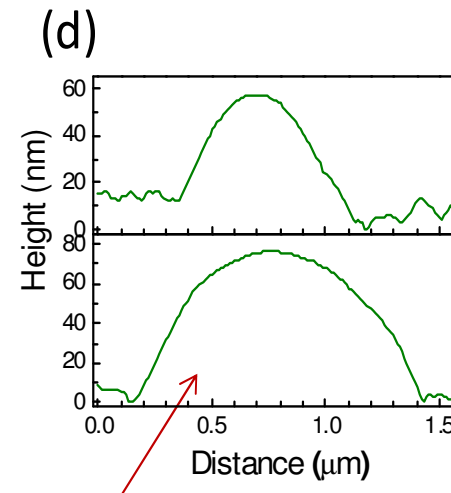
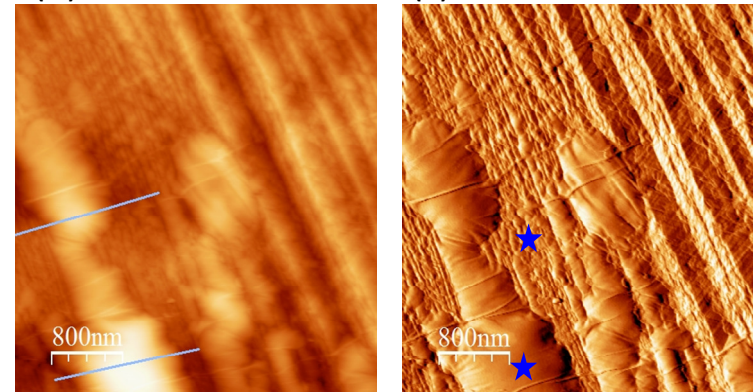
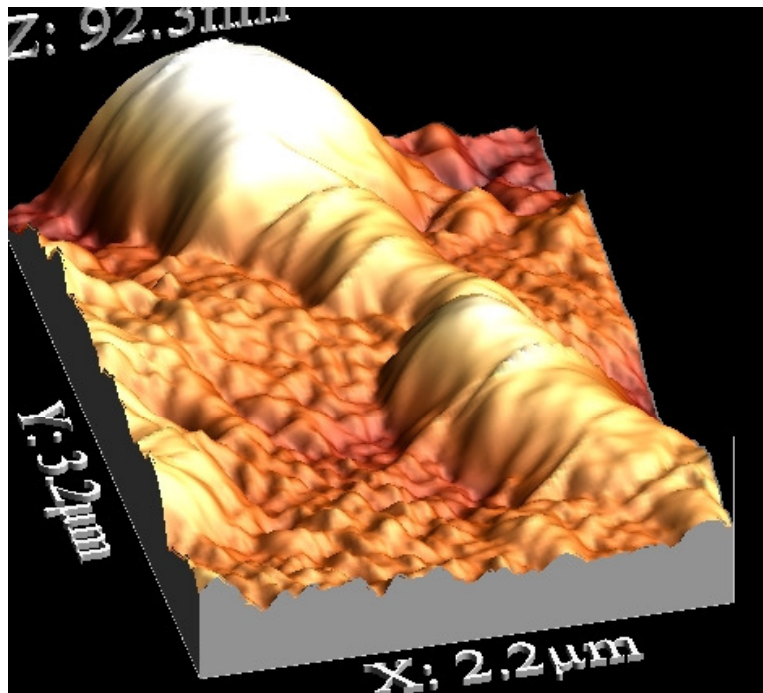
Interference in graphene bubbles



Graphene bubbles:
Raman characteristics of
free-standing graphene

Raman enhancement: 60
Bubble height 70 nm

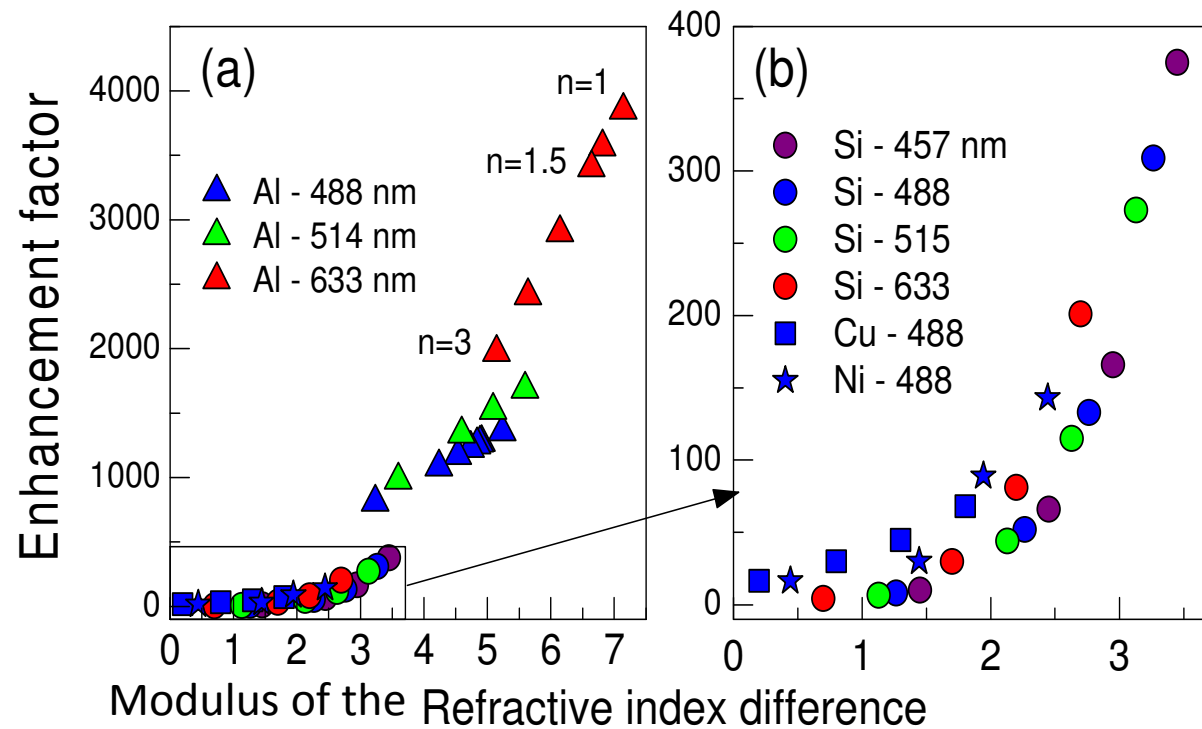
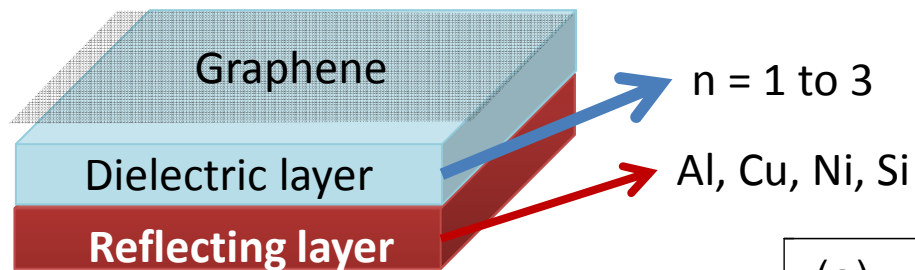
Interference enhancement by graphene bubbles



Bubbles: lateral size around few microns
height ~70 nm

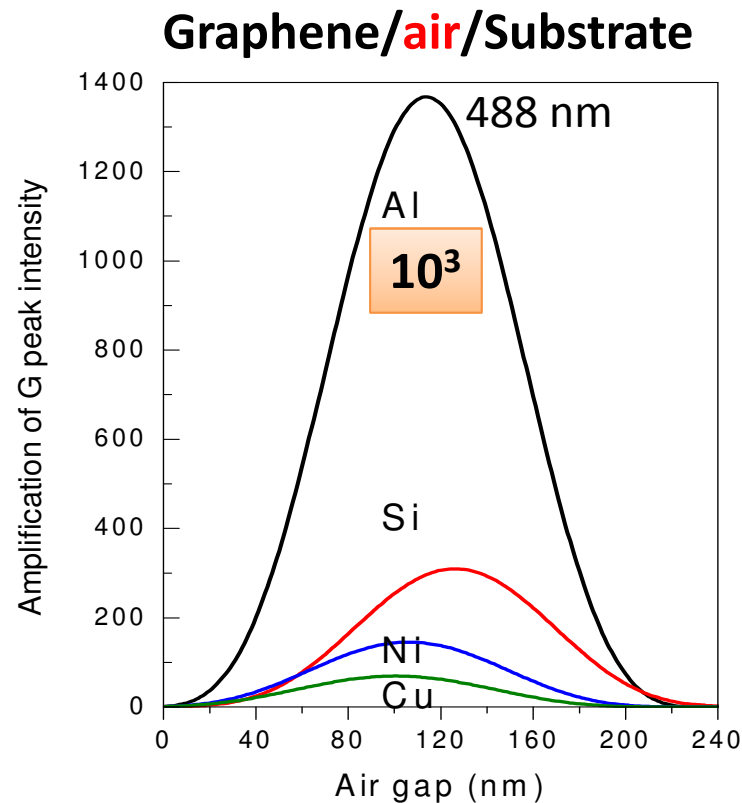
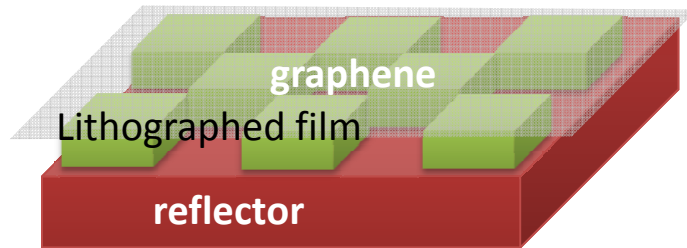
R. Ramírez-Jiménez et al. **Carbon** 105, 556 (2016)

General behavior of IERS

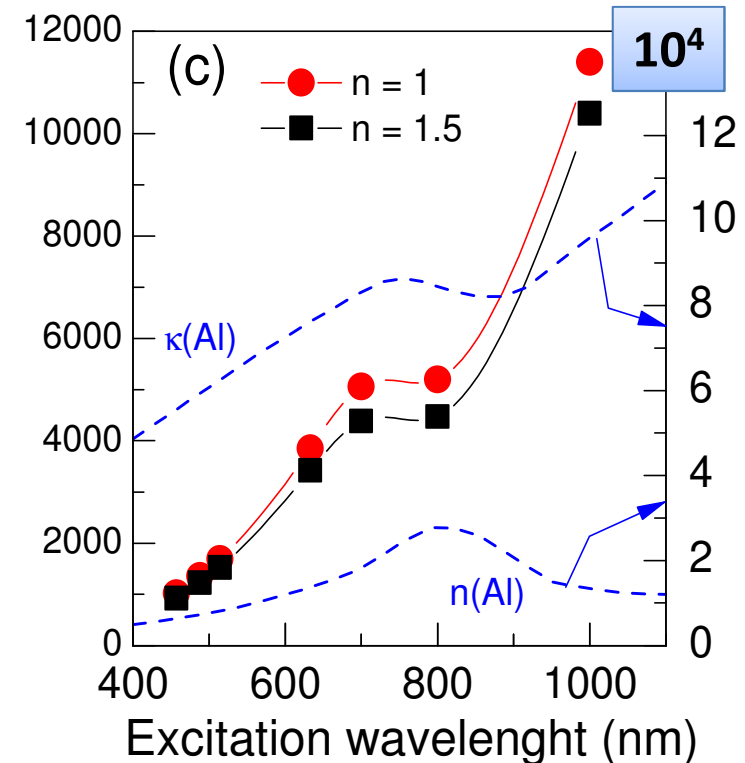


Low refractive index of the dielectric layer
High refractive index of the reflecting layer

Interference in Graphene/dielectric/Aluminium

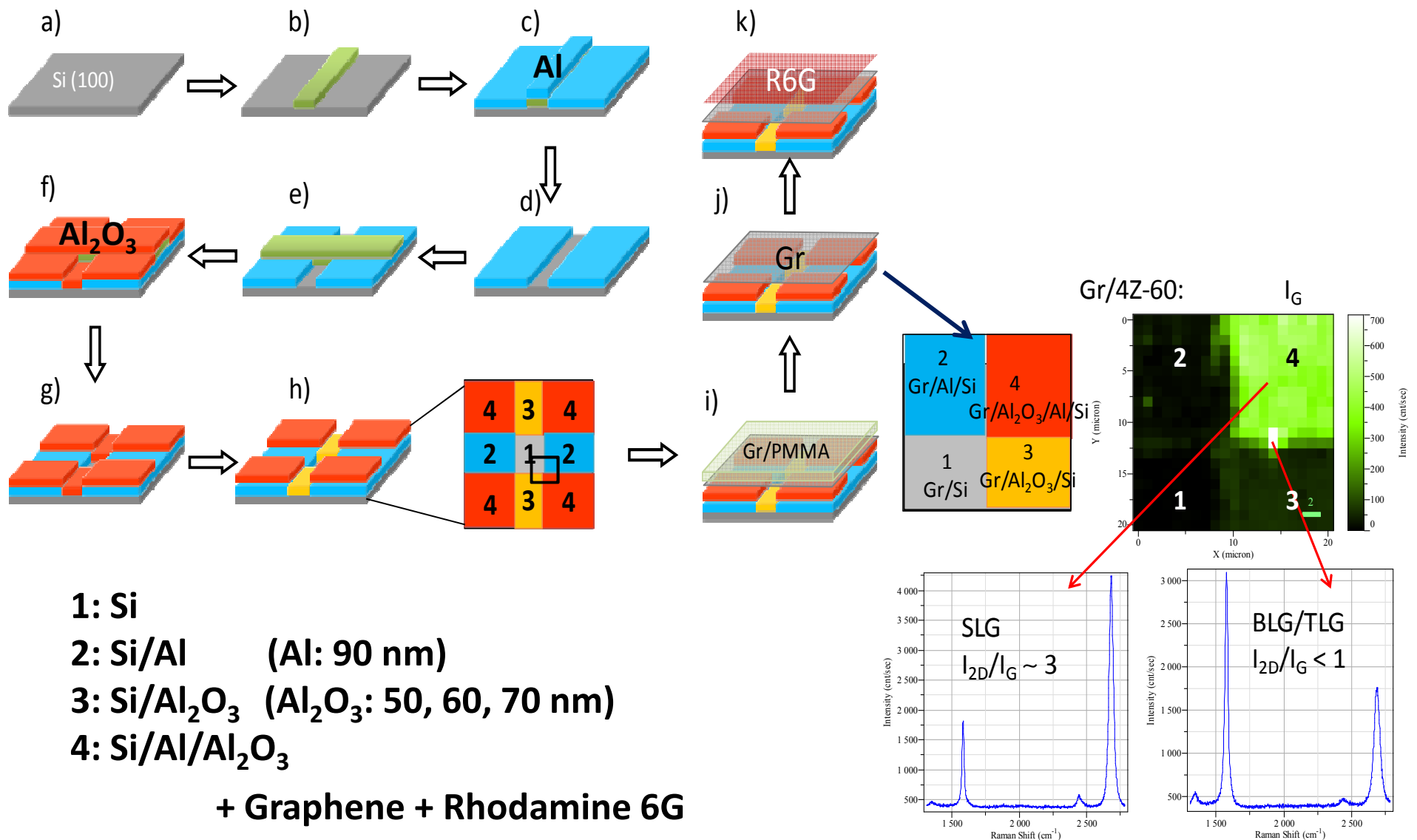


Graphene/dielectric/Al



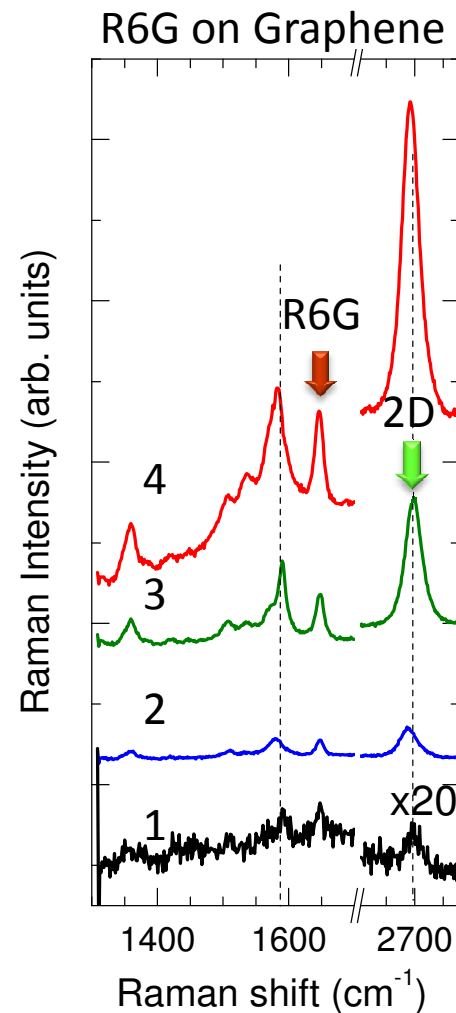
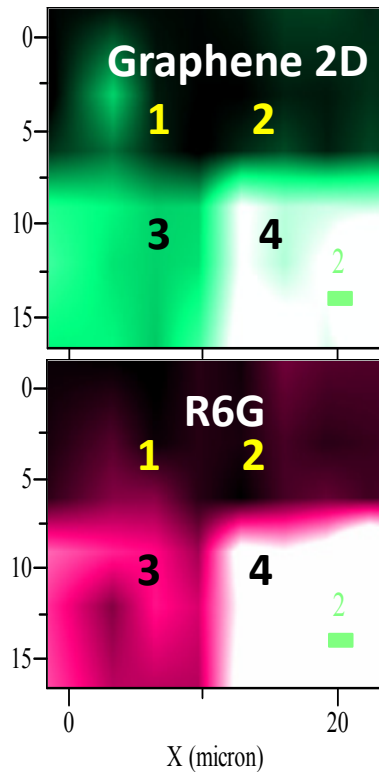
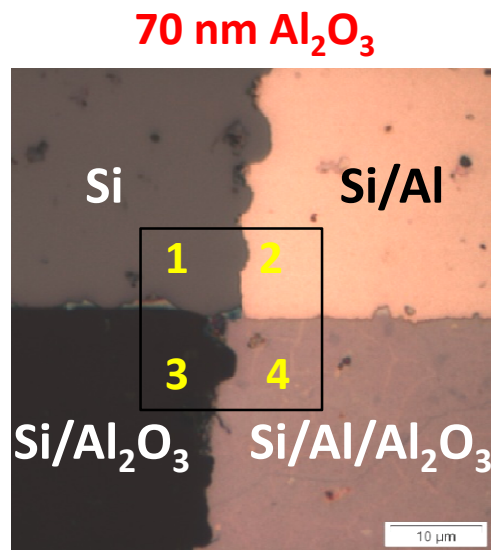
Raman enhancement up to **1400** is predicted for the system Al/air/graphene at 488 nm laser excitation and up to **12000** for 1000 nm

2- Heterostructures for interference : Si/Al/Al₂O₃

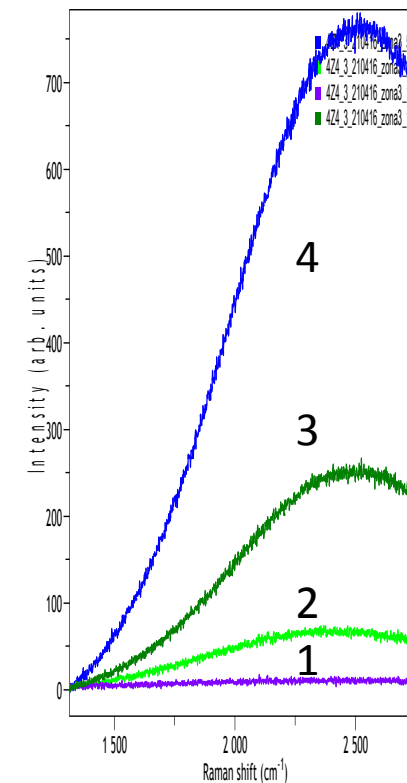


L. Alvarez-Fraga, et al. " ACS Appl. Mat. & Interfaces 9, 4119 (2017)

Si/Al/Al₂O₃ / Graphene / R6G



R6G without graphene

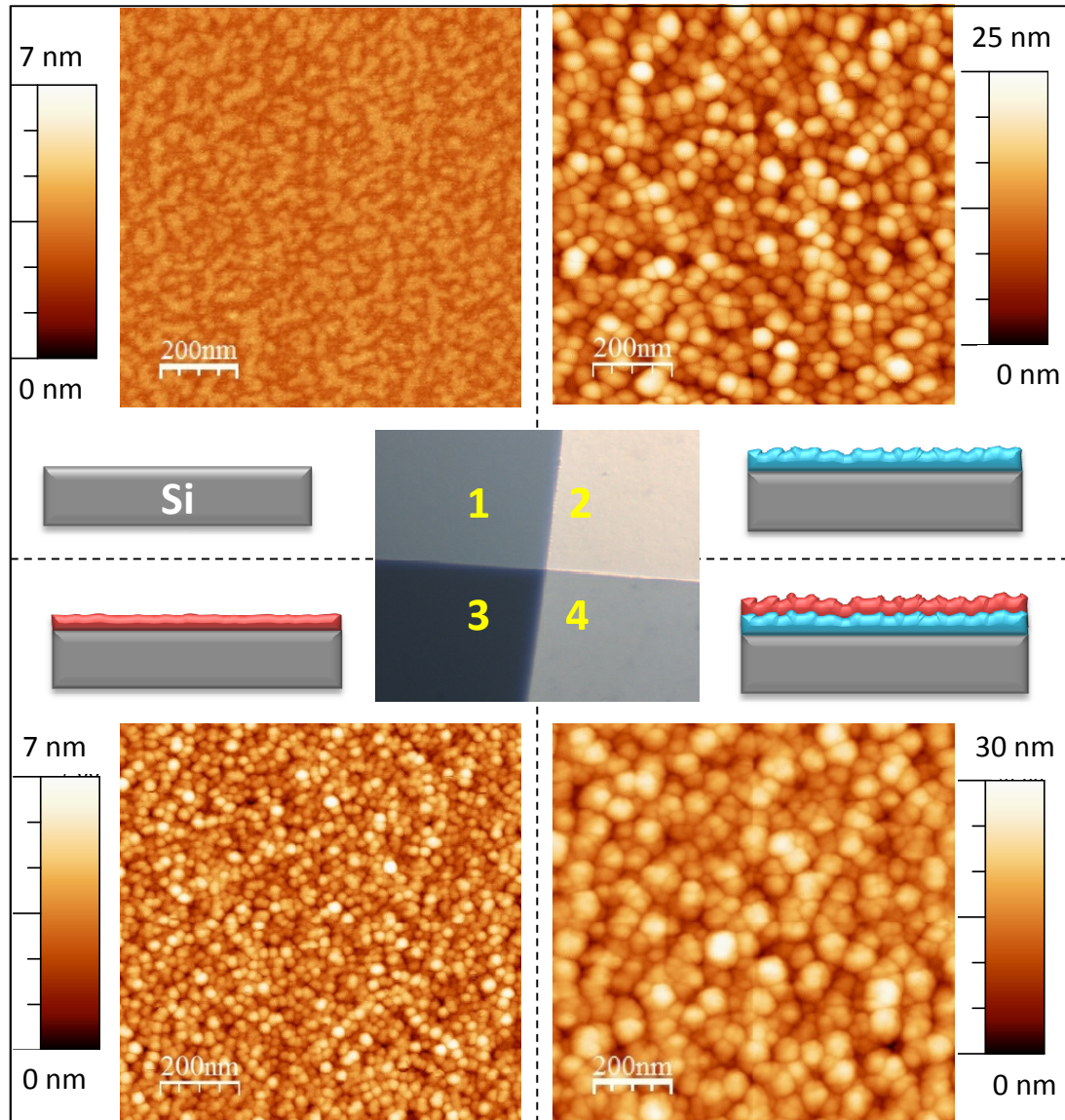


Al ₂ O ₃ (nm)	IERS 2D Calc	IERS 2D	IERS R6G
50	950	550	
60	1140	670	
70	820	350	150

R6G surface density = 2×10^{13} molecules/cm² = 1ML

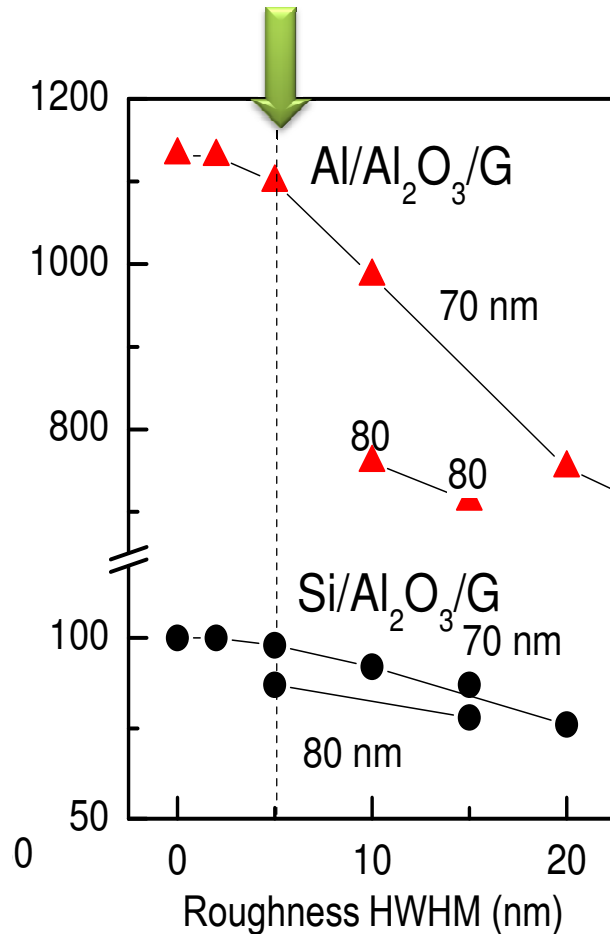
Factors limiting amplification

1: Si
0.43 nm RMS
FWHM=1.0 nm

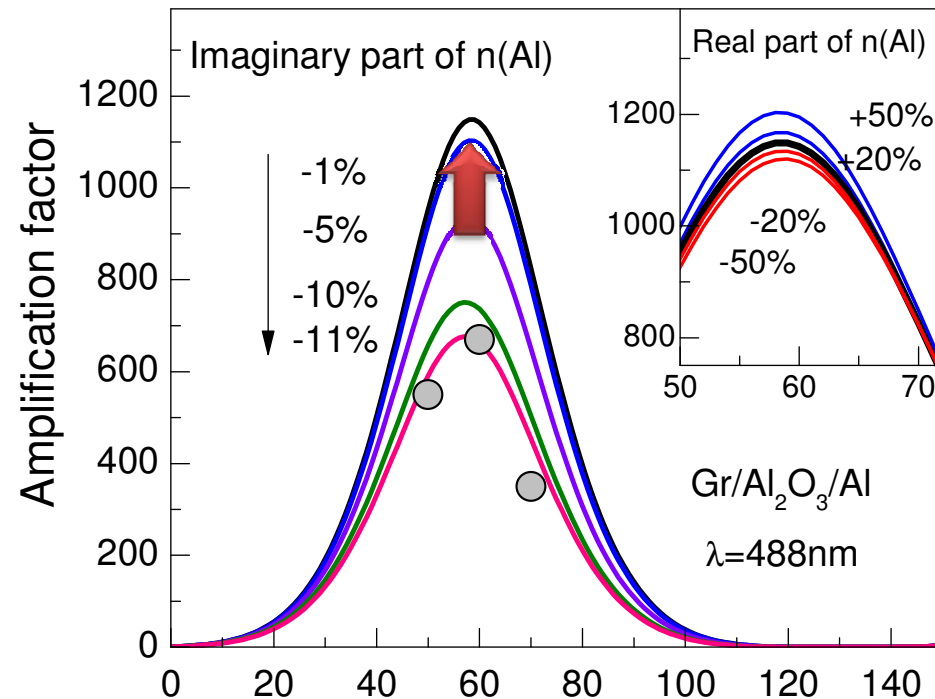


Factors limiting amplification

Roughness of the heterostructure

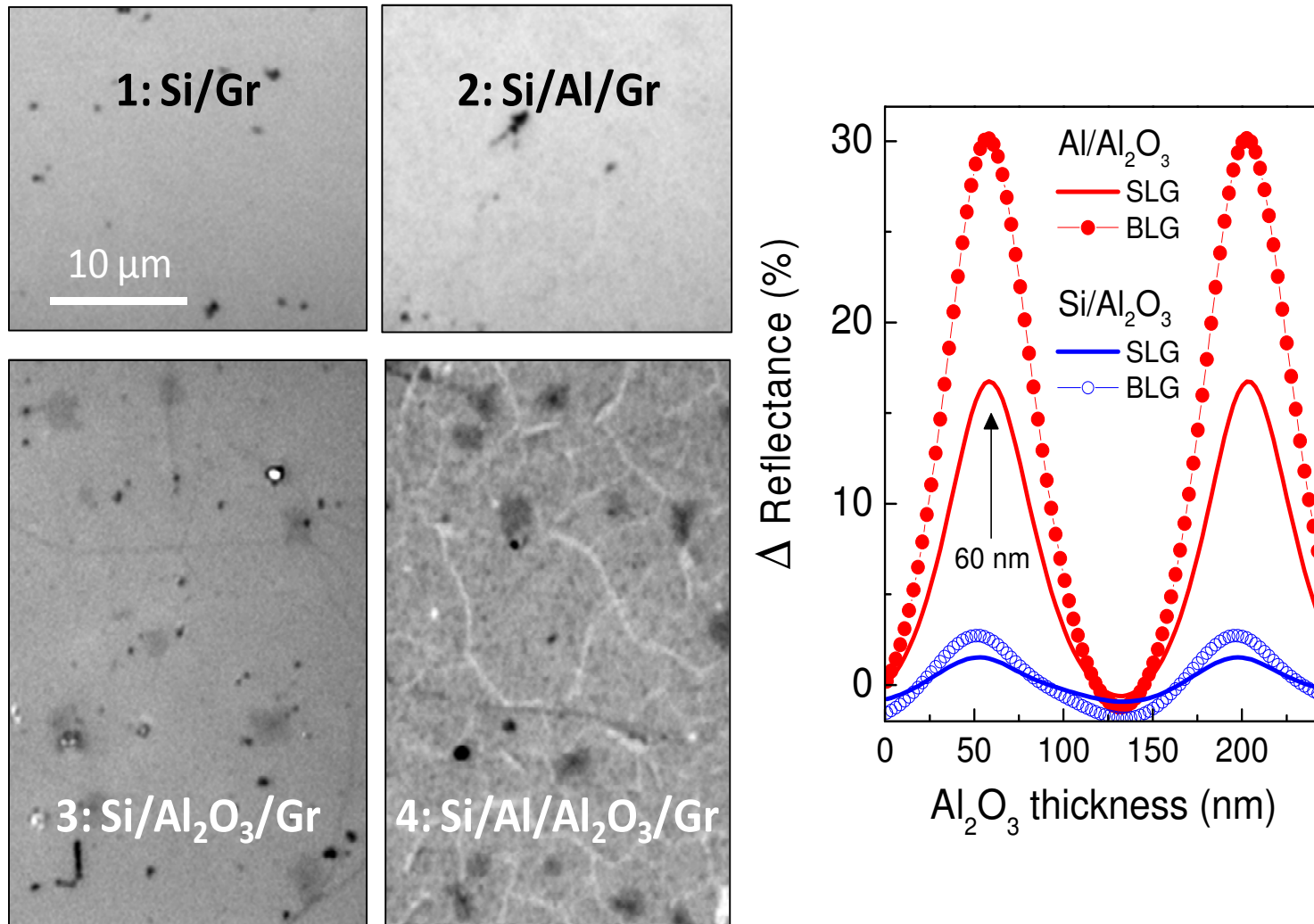


Refractive index of the Aluminum layer



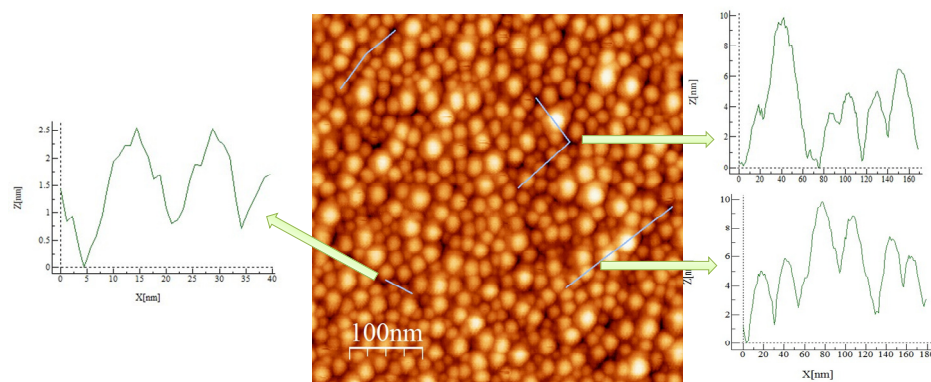
Improve Aluminum layer quality:
Decrease roughness and **increase layer density**
-> e-beam deposition of Al

Interference amplification in white light images



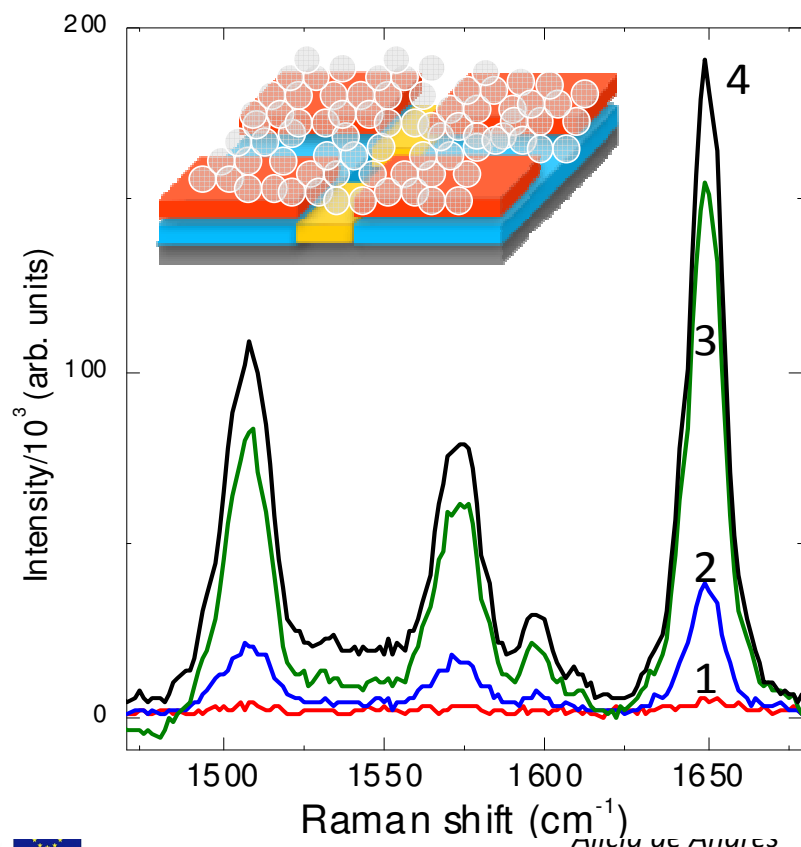
L. Alvarez-Fraga, et al. " **ACS Appl. Mat. & Interfaces** 9, 4119 (2017)

3- Combination of IERS and SERS



Ultrathin Ag film deposited on the IERS heterostructure

Ag film: bimodal size distribution:
big NPs ~ 40 nm $\varnothing$ ~ 10 nm height
small NPs ~ 20 nm $\varnothing$ ~ 3 - 5 nm height



IERS + SERS

4: Si/Al/Al₂O₃

3: Si/Al₂O₃

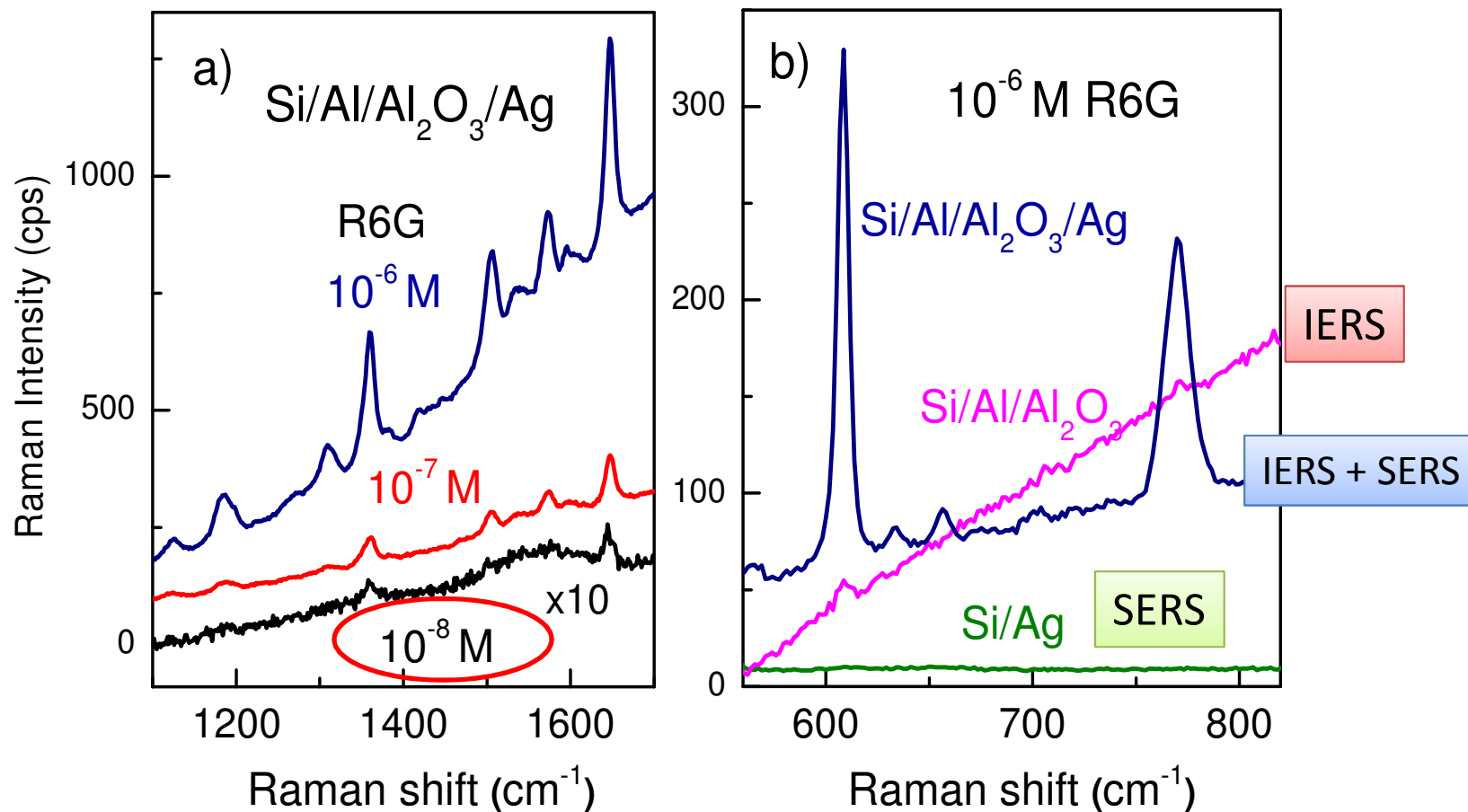
2: Si/Al

1: Si

+ Ag 1nm film

+ 1 ML R6G

IERS + SERS



L. Alvarez-Fraga, et al. " **ACS Appl. Mat. & Interfaces** 9, 4119 (2017)

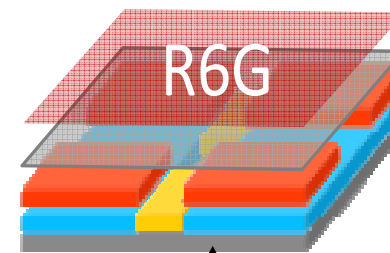
Conclusions

1- Interference enhancement:

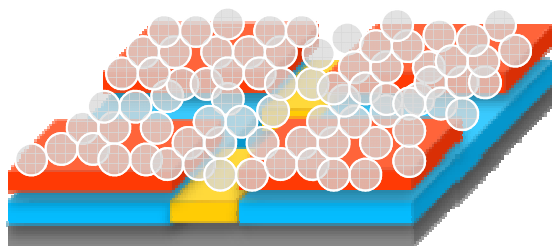
Optimum system: Al/air/Graphene $\rightarrow$ RE = **1400** for **488 nm**
12000 for **1000 nm**

Si/Al/Al₂O₃/Gr $\rightarrow$ RE $\cong$ **700** for **488nm**, limited by κ (Al)

Amplification of Raman signal and of **fluorescence** of the analyte
Increased contrast in optical images: optimum por 60 nm Al₂O₃



2- Combined IERS + SERS



Amplification factor of combined **IERS + SERS** platforms: **10⁵**
Detection of 10⁻⁸ M R6G

On going:

- * Increase SERS amplification.
Limitation: the Ag film has to be transparent enough
- Optimize Aluminum refractive index for IERS